ESS503 GID-5-EV03.3.1

ESS503 Ceramic Piezo-Resistive Pressure & Temperature Sensor Cell

MONOLITHIC THCIK-FILM | Al2O3 96%



■ Range: 0~2bar~100bar/600bar ■ Size:18mm*6.35mm; 18mm*3.5mm ■ Diaphragm Material: Ceramic Al2O3 96% ■ Power Supply: 2-30V ■ Long Term Stability: 0.3%/FS ■ NTC Thermistor ■ Working Temperature: -40...+135 °C

Description

ESS503 Monolithic Pressure & Temperature Sensor Cell are made with a Ceramic Base Plate and Diaphragm and work following the piezoresistive principle. With temperature sensor mounted, ESS503 can detect temperature change via NTC Thermistor.

By integrating an **NTC thermistor**, ESS503 can continuously monitor the temperature and apply real-time compensation to the pressure readings, and can provide the necessary temperature data, allowing a more comprehensive understanding of the environment.

The Wheatstone bridge is **Screen Printed** on one side of the flush ceramic diaphragm which is, in turn, glued to the sensor's body. The bridge faces the inside where a cavity is made and the diaphragm's opposite side can therefore be exposed directly to the medium to be measured.

As the same as ESS501 and ESS502, ESS503 is also available with two kinds size: **18*6.35mm and 18*3.5mm** (thin type).

Key Features & Benefits

- Pressure range 0-2bar-100bar/600bar
- Excellent resistance to corrosion and abrasion
- Integrated with NTC Thermistor
- Thermally compensated
- Extended customization
- Extended choice of measuring ranges

Application

- Cooling equipment & A/C system
- Automotive and vehicle
- Industrial process control
- HVAC system
- Refrigeration equipment
- Air conditioning unit

Technical Characteristics

Parameter	Unit	Description			
Sensor type	-	absolute (A), gauge (R) or sealed gauge (S)			
Technology	-	Piezoresistive (Ceramic Thick Film)			
Diaphragm material	-	Ceramic Al ₂ O ₃ 96% (standard), 99.6% or sapphire (on request)			
Weight	g	≤ 8 (ceramic cell only)			
Response time	ms	≤1			



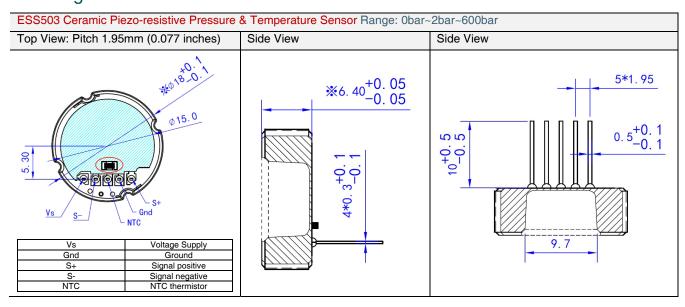
10 million 0 bar to Pnom pressure cycles

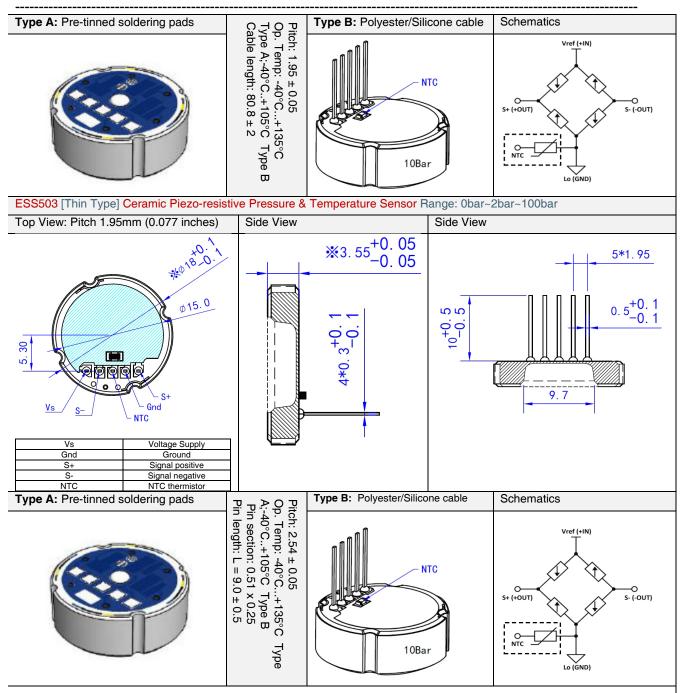
Supply voltage	VDC	VDC 230												
Offset		mv/v	2 ±4 (Other nominal values available on request)											
-		mA	≤ 1.3 @ 10V											
Ourient			≤100ppm/°C@-40°C~120°C											
TCR			11 / 5											
NTC		°C	10kΩ±1.5%@25°C, B=3950K											
Operating temperature			-40+135 (-40 °F+275 °F)											
Storage temperature		°C	-40+150 (-40 °F+302 °F)											
Impedance		kΩ	11 ± 30%											
Nominal	bar	0.5 *	1*	2	5	10	20	50	100	200	400	600	800 *	
pressure FSO	psi	7	14	29	73	145	290	725	1450	2900	5800	8700	11600	
Overload	bar	1	2	4	10	15	35	100	150	350	500	750	1000	
pressure	psi	14	29	58	145	217	507	1450	2175	5075	7250	10875	14500	
Burst pressure	bar	2	3	6	15	25	65	120	200	500	650	950	1250	
	psi	29	43	87	217	362	942	1740	2900	7250	9425	13775	18125	
Vacuum	bar	-0.1	-0.5	-0.5	-1	-1	-1	-1	-1	-1	-1	-1	-1	
capability	psi	-1.4	-7	-7	-14	-14	-14	-14	-14	-14	-14	-14	-14	
Туре	-	R	A/R/S	A/R/S	A/R/S	A/R/S	A/R/S	A/R/S	S	S	S	S	S	
Total thickness	mm/in		6.40±0.05/2.51±0.2											
	mm/in		$3.55\pm0.05/1.40\pm0.2$; for thin type											
Sensitivity	mv/v	1.4-	2.0-3.6	2.3-3.5	2.3-4.0	3.1-5.5	2.4-4.0	4.0-6.0	3.0-4.8	2.5-3.9	3.1-4.8	3.1-4.8	2.0-3.5	
Accuracy	%/fs	0.4/0	0.3/0.9	0.3/0.6	0.2/0.4	0.2/0.5	0.2/0.5	0.2/0.5	0.2/0.5	0.4/0.9	0.5/1.0	0.5/1.0	0.5/1.0	
Thermal offset shift(typ./max.)	%/fs/k	± 0.0	05 / ± 0.040			25 °C85 °C (77				°F185 °F)				
Thermal span shift	%/fs/k	≤ ± 0	≤±0.010 ≤±0.012 ≤±0.014				-25 °C0 °C / 70 °C85 °C (-13 °F				158 °F) 32 °F / 158 °F185 °F) 13 °F / 185 °F275 °F)			
Reliability tests	-	1000	hours @85	°C (185 °F) & 85 %RH	l	500 thermal shocks -40°C+150 °C (-40 °F +302 °F)							

1000 hours burn-in @150 °C (302 °F) 10 mi
Tests performed at 25 °C in Eastsensor housings, unless otherwise specified. Different housings may affect performances.

- 1. Psi values for reference only. 2. The sensitivity of each production batch is constant, within the indicated range and with minimal dispersion.
- $\textbf{3.} \textit{Accuracy} = \sqrt{\textit{NonLinearity}^2 + \textit{Hysteresis}^2 + \textit{NonRepeatability}^2}, \textit{terminal based}.$
- 4. All technical characteristics will remain within indicated ranges performing the above-mentioned reliability tests. 5. Please consult manufacturer when pressure range with **

Drawing





- 1. Storage Conditions: Store at 10~35°C with ≤ 70% RH. Avoid places that are too hot, exposed to direct sunlight, dusty, or have corrosive gases. The metal pins can easily oxidize in the air, so it's recommended to use the product within 10 days after unpacking. Under proper storage conditions, the soldering validity is 12 months. If stored for more than 12 months, the ceramic core needs to be rechecked for solderability and can only be used if it passes inspection.
- 2. Product Installation Pressure: During crimping installation, the crimping pressure should not exceed 20KN, and the direct pressure on the core should not exceed 5KN. Excessive force may damage the core structure or cause abnormal output signals. The ceramic core should not come into direct contact with hard objects like a metal casing to avoid significant internal stress and unstable output.
- 3. Sealing Recommendations: When using sealing rings, ensure that the sealing ring is centered with the elastic diaphragm and without uneven force. The inner diameter of the sealing ring should be > 11.0mm and the outer diameter < 16.0mm after compression deformation.
- 4. Solder Pads: The pressure core PIN is constructed of nickel-tin copper. The welding hole for the PIN measures 0.7mm, with a pad width exceeding 0.5mm. The soldering temperature must not exceed 370 °C, with each soldering session limited to under 3 seconds and a maximum of 3 sessions.



Ordering Procedure

ESS5	Ceram	c Piezoresi	istive Pre	ssure Se	ensor						
	Code	Model	Model								
	01	Pressu	Pressure Sensor Cell, Monolithic 18*6.35mm								
	01 Thin	Pressu	Pressure Sensor Cell, Monolithic 18*3.35mm								
	01-I	Pressu	ire Senso	Electronics on PCB							
	01-V	Pressu	ire Senso	or Modul	e, Monolit	hic (with po	ocb) 0.5-4.5V; Electronics on PCB				
	01-IIC	Pressu	ire Senso	or Modul	e, Monolit	nic (with pcb) I2C Output; Electronics on PCB					
	02	Pressu	ire Senso	or Cell, F	lush diaph	nragm 18*6.35mm					
	02 Thin					hragm 18*3.35mm					
	02-I	Pressu	ire Senso	or Modul	20mA; Electronics on PCB						
	02-IOC		ure Sensor Module, Flush diaphragm (with pcb) 4-20mA; Electronics on Ceramic								
	02-V		ssure Sensor Module, Flush diaphragm (with pcb) 0.5-4.5V; Electronics on PCB								
	02-VOC		essure Sensor Module, Flush diaphragm (with pcb) 0.5-4.5V; Electronics on Ceramic								
	02-IIC		essure Sensor Module, Flush diaphragm (with pcb) I2C Output; Electronics on PCB								
	02-IICO		ssure Sensor Module, Flush diaphragm (with pcb) I2C Output; Electronics on Ceramic								
	03			•		rature sensor mounted), Monolithic 18*6.35mm					
	03 Thir			or Cell (w	vith tempe), Monolithic 18*3.35mm			
		Code	Span			Code	Span				
		R01 R02		oar [07		R07	050 bar	[0720psi]			
			01 bar [014psi]			R08	0100 bar	<u> </u>			
		R03	02 bar [029psi] 05 bar [072psi]			R09	0200 bar	[02900psi]			
		R04				R10	0400 bar	[05800psi]			
		R05	010 b		.145psi]	R11	0600 bar [08700psi]				
		R06	020 b		.290psi]	R12	0800 bar	[011600psi]			
			Code Pressure Type								
			R	Gauge							
				A Absolute							
			S		Gauge		4				
				Code	Without	ty adjustme	ent				
				9	On requ	oot					
				9	Code		l officet				
					0		rmal offset 06 % FS/K (not thermally compensated)				
					1						
					2	≤±0.04 % FS/K					
						Code	≤±0.02 % FS/K Code Termination type				
						02	••				
						03	· pe, · · · e · · · · · · · p.···e · p.··e · · · · · · · · · · · · · · · · · ·				
							Code	Additional coating			
							1	Without			
							2	Parylene coating			
ESS5	03	R10	R	0	2	03	1	. ,			

Note: ① Extremely attention must be paid to sensor installation process to avoid any miss conduction that affect the sensor performance, ② please protect the diaphragm and the compensated board carefully to prevent any damage. ③ Please contact us if your requested working temperature lower than -20 °C;